

Docket No.: V0195.0008
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Franz Hofmann et al.

Application No.: 10/768,971

Confirmation No.: 4544

Filed: January 30, 2004

Art Unit: 2815

For: Fin field-effect transistor and method for
producing a fin field effect-transistor

Examiner: E. J. Wojciechowicz

AMENDMENT AFTER FINAL ACTION UNDER 37 C.F.R. 1.116

MS AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

Enter
BJ
In response to the Advisory Action dated October 2, 2006, and in further response to the Office Action dated March 23, 2006, the following Remarks are respectfully submitted.

Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.